



PNP PRE-BIASED DUAL TRANSISTOR IN SOT363

Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- · Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DDA (XXXX) UQ are suitable for automotive applications requiring specific change control; these parts are AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mec	hanica	l Data
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- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ®3
- Weight: 0.006 grams (Approximate)

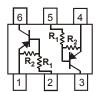
Part Number	R1 (NOM)	R2 (NOM)
DDA124EU	22kΩ	22kΩ
DDA144EU	47kΩ	47kΩ
DDA114YU	10kΩ	47kΩ
DDA123JU	2.2kΩ	47kΩ
DDA114EU	10kΩ	10kΩ

Part Number	R1 Only
DDA113TU	1kΩ
DDA143TU	4.7kΩ
DDA114TU	10kΩ

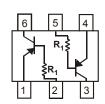
SOT363







R1, R2



R1 Only

Device Schematic

Ordering Information (Notes 4, 5)

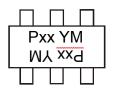
Product	Status	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DDA124EU-7-F	Active	Standard	P17	7	8	3,000
DDA124EUQ-7-F	Active	Automotive	P17	7	8	3,000
DDA124EUQ-13-F	Active	Automotive	P17	13	8	10,000
DDA144EU-7-F	Active	Standard	P20	7	8	3,000
DDA144EUQ-7-F	Active	Automotive	P20	7	8	3,000
DDA114YU-7-F	Active	Standard	P14	7	8	3,000
DDA114YUQ-7-F	NRND (Use ADA114YUQ)	Automotive	P14	7	8	3,000
DDA123JU-7-F	Active	Standard	P06	7	8	3,000
DDA114EU-7-F	Active	Standard	P13	7	8	3,000
DDA114EUQ-7-F	NRND (Use ADA114EUQ)	Automotive	P13	7	8	3,000
DDA113TU-7-F	Active	Standard	P01	7	8	3,000
DDA143TU-7-F	Active	Standard	P07	7	8	3,000
DDA143TUQ-7-F	Active	Automotive	P07	7	8	3,000
DDA143TUQ-13-F	Active	Automotive	P07	13	8	10,000
DDA114TU-7-F	Active	Standard	P12	7	8	3,000
DDA114TUQ-7-F	Active	Automotive	P12	7	8	3,000
DDA114TUQ-13-F	Active	Automotive	P12	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
- 5. NRND = Not Recommended for New Design.



Marking Information



Pxx = Product Type Marking Code (See Ordering Information)

YM = Date Code Marking

Y = Year (ex: I = 2021)

M = Month (ex: 9 = September)

Date Code Key

Year	2018		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	F			J	K	L	М	N	0	Р	R	S
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Charac	teristic	Symbol	Value	Unit
Supply Voltage (1) to (6) and (4) to (3)		V _{CC}	-50	V
DDA124EU		Vin	+10 to -40 +10 to -40 +6 to -40 +5 to -12 +10 to -40 +5V Max +5V Max +5V Max	V
Output Current	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU DDA113TU DDA143TU DDA114TU	lo	-30 -30 -70 -100 -50 -100 -100	mA
Output Current		I _{C(max)}	-100	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 6, 7)	P_{D}	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

- 6. Mounted on FR-4 PC Board with minimum recommended pad layout. 7. 150mW per element must not be exceeded.



Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

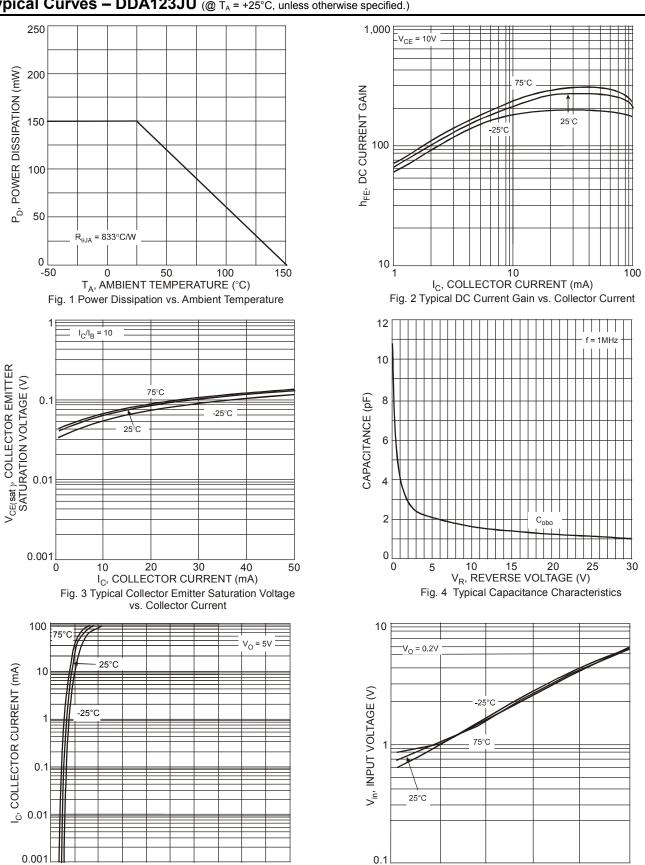
Characteristic (DDA113TU & DDA143TU & DDA114TU only)	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	_	_	V	I _C = -50μA
Collector-Emitter Breakdown Voltage	BV_{CEO}	-50	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -50μA
Collector Cutoff Current	I _{CBO}	_		-0.5	μΑ	V _{CB} = -50V
Emitter Cutoff Current	I _{EBO}	_		-0.5	μΑ	V _{EB} = -4V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	_	-0.3	V	$I_{C}/I_{B} = -2.5 mA / -0.25 mA$ DDA143TU $I_{C}/I_{B} = -1 mA / -0.1 mA$ DDA114TU $I_{C}/I_{B} = -10 mA / -1 mA$ DDA113TU
DC Current Transfer Ratio	h _{FE}	100 160	250 —	600 600		I_C = -1mA, V_{CE} = -5V I_C = -1mA, V_{CE} = -5V DDA143TU/Q
Input Resistor (R ₁) Tolerance	ΔR_1	-30	_	+30	%	
Gain-Bandwidth Product (Note 8)	f _T	_	250	_	MHz	$V_{CE} = -10V$, $I_E = 5mA$, $f = 100MHz$

Characterist	ic	Symbol	Min	Тур	Max	Unit	Test Condition
	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	V _{I(off)}	-0.5 -0.5 -0.3 -0.5 -0.5	-1.1 -1.1 — — -1.1	_	,	V _{CC} = -5V, I _O = -100μA
Input Voltage	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	V _{I(on)}	_	-1.9 -1.9 -1.9	-3.0 -3.0 -1.4 -1.1 -3.0	V	V _O = -0.3, I _O = -5mA V _O = -0.3, I _O = -2mA V _O = -0.3, I _O = -1mA V _O = -0.3, I _O = -5mA V _O = -0.3, I _O = -10mA
Output Voltage	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	V _{O(on)}	_	-0.1	-0.3	V	I _O /I _I = -10mA / -0.5mA I _O /I _I = -10mA / -0.5mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -5mA / -0.25mA I _O /I _I = -10mA / -0.5mA
Input Current	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	II			-0.36 -0.18 -0.88 -3.6 -0.88	mA	V ₁ = -5V
Output Current		I _{O(off)}	_	_	-0.5	μA	V _{CC} = -50V, V _I = -0V
DC Current Gain	DDA124EU DDA124EUQ DDA144EU DDA114YU DDA123JU DDA114EU	Gı	56 60 68 68 80 30	_	_	_	V _O = -5V, I _O = -5mA V _O = -5V, I _O = -5mA V _O = -5V, I _O = -5mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -10mA V _O = -5V, I _O = -5mA
Input Resistor (R ₁) Tolerance	,	ΔR_1	-30	_	+30	%	_
Resistance Ratio Tolerance		R ₂ /R ₁	-20		+20	%	
Gain-Bandwidth Product (Note 8)	f _T	_	250		MHz	$V_{CE} = -10V, I_{E} = -5mA, f = 100MHz$

Note: 8. Transistor - For Reference Only.



Typical Curves - DDA123JU (@ T_A = +25°C, unless otherwise specified.)



5 6

V_{IN}, INPUT VOLTĂGE (V)

Fig. 5 Collector Current vs. Input Voltage

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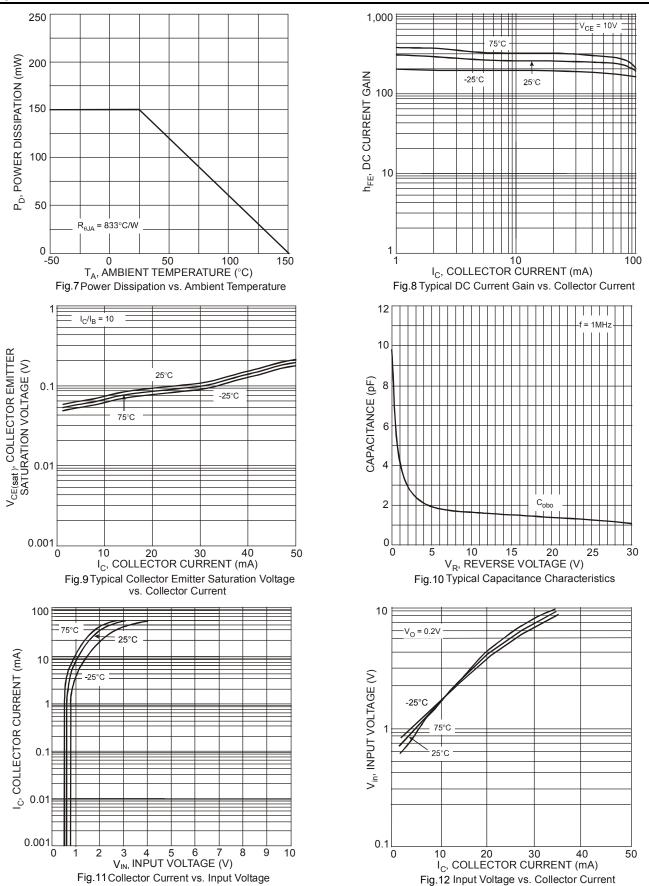
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I_C, COLLECTOR CURRENT (mA)

Fig. 6 Input Voltage vs. Collector Current



Typical Curves - DDA114TU (@ T_A = +25°C, unless otherwise specified.)

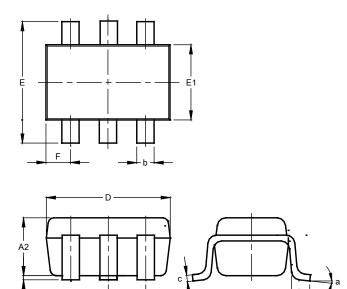




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363

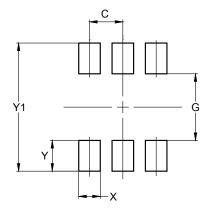


SOT363									
Dim	Min	Min Max Typ							
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.10	0.30	0.25						
C	0.10	0.22	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
е	C).650 E	SC						
F	0.40	0.45	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All I	Dimen	sions	in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
Y1	2.500



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